www.ti.com

SCES677A - SEPTEMBER 2006-REVISED AUGUST 2009

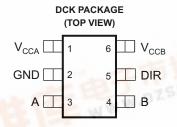
SINGLE-BIT DUAL-SUPPLY BUS TRANSCEIVER WITH CONFIGURABLE VOLTAGE TRANSLATION AND 3-STATE OUTPUTS

Check for Samples: SN74LVC1T45-Q1

FEATURES

- Qualified for Automotive Applications
- Customer-Specific Configuration Control Can Be Supported Along With Major-Change Approval
- Fully Configurable Dual-Rail Design Allows
 Each Port to Operate Over the Full 1.65-V to
 5.5-V Power-Supply Range
- V_{CC} Isolation Feature If Either V_{CC} Input Is at GND, Both Ports Are in the High-Impedance State
- DIR Input Circuit Referenced to V_{CCA}
- ±24-mA Output Drive at 3.3 V
- I_{off} Supports Partial-Power-Down Mode Operation

- Maximum Data Rates
 - 420 Mbps (3.3-V to 5-V Translation)
 - 210 Mbps (Translate to 3.3 V)
 - 140 Mbps (Translate to 2.5 V)
 - 75 Mbps (Translate to 1.8 V)



See mechanical drawings for dimensions.

DESCRIPTION/ORDERING INFORMATION

This single-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA} . V_{CCA} accepts any supply voltage from 1.65 V to 5.5 V. The B port is designed to track V_{CCB} . V_{CCB} accepts any supply voltage from 1.65 V to 5.5 V. This allows for universal low-voltage bidirectional translation between any of the 1.8-V, 2.5-V, 3.3-V, and 5-V voltage nodes.

The SN74LVC1T45 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input activate either the B-port outputs or the A-port outputs. The device transmits data from the A bus to the B bus when the B-port outputs are activated and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ}.

The SN74LVC1T45 is designed so that the DIR input is powered by V_{CCA}.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, then both ports are in the high-impedance state.

ORDERING INFORMATION(1)

T _A	PACKAGE (2)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 105°C	SOT (SC-70) - DCK	Reel of 3000	SN74LVC1T45TDCKRQ1	5TR

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



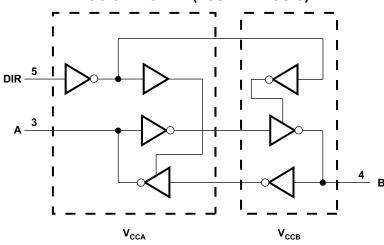


FUNCTION TABLE(1)

INPUT DIR	OPERATION
L	B data to A bus
Н	A data to B bus

(1) Input circuits of the data I/Os always are active.

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

	,		MIN	MAX	UNIT	
V _{CCA} V _{CCB}	Supply voltage range		-0.5	6.5	V	
VI	Input voltage range (2)	-0.5	6.5	V		
Vo	Voltage range applied to any output in the high-impedance or power	-0.5	6.5	V		
V	Voltage range applied to any output in the high or law state (2) (3)	A port	-0.5	V _{CCA} + 0.5	V	
Vo	Voltage range applied to any output in the high or low state (2) (3)	B port	-0.5	V _{CCB} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA	
lok	Output clamp current	V _O < 0		-50	mA	
Io	Continuous output current			±50	mA	
	Continuous current through V _{CC} or GND			±100	mA	
θ_{JA}	Package thermal impedance (4)	DCK package		259	°C/W	
T _{stg}	Storage temperature range	·	-65	150	°C	

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

⁽³⁾ The value of V_{CC} is provided in the recommended operating conditions table.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51-7.



SCES677A - SEPTEMBER 2006-REVISED AUGUST 2009

Recommended Operating Conditions (1) (2) (3)

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.65	5.5	V
V _{CCB}	Supply voltage				1.65	5.5	V
			1.65 V to 1.95 V		$V_{CCI} \times 0.65$		
.,	High-level	Data inputs (4)	2.3 V to 2.7 V		1.7		V
V_{IH}	input voltage	Data inputs 7	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		V _{CCI} × 0.7		
			1.65 V to 1.95 V			V _{CCI} × 0.35	
.,	Low-level	Data inputs ⁽⁴⁾	2.3 V to 2.7 V			0.7	V
V_{IL}	input voltage	Data inputs (7)	3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCI} \times 0.3$	
			1.65 V to 1.95 V		V _{CCA} × 0.65		
. ,	High-level	515 (()) (5)	2.3 V to 2.7 V		1.7		.,
V_{IH}	input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	3 V to 3.6 V		2		V
			4.5 V to 5.5 V		$V_{CCA} \times 0.7$		
			1.65 V to 1.95 V			$V_{CCA} \times 0.35$	
. ,	Low-level		2.3 V to 2.7 V			0.7	.,
V_{IL}	input voltage		3 V to 3.6 V			0.8	V
			4.5 V to 5.5 V			$V_{CCA} \times 0.3$	
V _I	Input voltage	1			0	5.5	V
Vo	Output voltage				0	V _{cco}	V
				1.65 V to 1.95 V		-4	
	I Pale Java Laudavid			2.3 V to 2.7 V		-8	4
Іон	High-level output	current		3 V to 3.6 V		-24	mA
				4.5 V to 5.5 V		-32	
				1.65 V to 1.95 V		4	
ı	Lour lovel output	ou uma n t		2.3 V to 2.7 V		8	 Λ
l _{OL}	Low-level output	current		3 V to 3.6 V		24	mA
				4.5 V to 5.5 V		32	
			1.65 V to 1.95 V			20	
	Input transition rise or fall rate	Data innuta	2.3 V to 2.7 V			20	
Δt/Δv		Data inputs	3 V to 3.6 V			10	ns/V
	noc or rail rate		4.5 V to 5.5 V			5	
		Control inputs	1.65 V to 5.5 V			5	
T _A	Operating free-air	temperature			-40	105	°C

V_{CCI} is the V_{CC} associated with the input port.

 ⁽¹⁾ V_{CCI} is the V_{CC} associated with the input port.
 (2) V_{CCO} is the V_{CC} associated with the output port.
 (3) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 (4) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
 (5) For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.



Electrical Characteristics (1) (2)

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDIT	IONS	V _{CCA}	V _{CCB}	Т,	λ = 25°C		T _A = -40		UNIT
						MIN	TYP	MAX	MIN	MAX	
		I _{OH} = -100 μA		1.65 V to 4.5 V	1.65 V to 4.5 V				V _{CCO} - 0.1		
		$I_{OH} = -4 \text{ mA}$		1.65 V	1.65 V				1.2		
V _{OH}		$I_{OH} = -8 \text{ mA}$	$V_I = V_{IH}$	2.3 V	2.3 V				1.9		V
		$I_{OH} = -24 \text{ mA}$		3 V	3 V				2.3		
		$I_{OH} = -32 \text{ mA}$		4.5 V	4.5 V				3.8		
		I _{OL} = 100 μA		1.65 V to 4.5 V	1.65 V to 4.5 V					0.1	
		I _{OL} = 4 mA		1.65 V	1.65 V					0.45	
V_{OL}		I _{OL} = 8 mA	$V_I = V_{IL}$	2.3 V	2.3 V					0.4	V
		I _{OL} = 24 mA		3 V	3 V					0.65	
		I _{OL} = 32 mA		4.5 V	4.5 V					0.65	
I _I	DIR	$V_I = V_{CCA}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±4	μΑ
	A port	\\ -=\\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	,	0 V	0 to 5.5 V			±1		±10	
I _{off}	B port	V_I or $V_O = 0$ to 5.5 V_I		0 to 5.5 V	0 V			±1		±10	μA
I _{OZ}	A or B port	$V_O = V_{CCO}$ or GND		1.65 V to 5.5 V	1.65 V to 5.5 V			±1		±10	μA
				1.65 V to 5.5 V	1.65 V to 5.5 V					10	
I _{CCA}		$V_I = V_{CCI}$ or GND,	$I_O = 0$	5.5 V	0 V					4	μA
				0 V	5.5 V					-10	
				1.65 V to 5.5 V	1.65 V to 5.5 V					10	
I _{CCB}		$V_I = V_{CCI}$ or GND,	$I_O = 0$	5.5 V	0 V					-10	μΑ
				0 V	5.5 V					4	
I _{CCA} + I ₀	ССВ	$V_I = V_{CCI}$ or GND,	I _O = 0	1.65 V to 5.5 V	1.65 V to 5.5 V					20	μΑ
	A port	A port at V _{CCA} – 0.6 DIR at V _{CCA} , B port								50	
ΔI _{CCA}	DIR	DIR at V _{CCA} – 0.6 V B port = open, A port at V _{CCA} or GI		3 V to 5.5 V	3 V to 5.5 V					50	μA
ΔI _{CCB}	B port	B port at V _{CCB} – 0.6 DIR at GND, A port		3 V to 5.5 V	3 V to 5.5 V					50	μA
Ci	DIR	$V_I = V_{CCA}$ or GND		3.3 V	3.3 V		2.5				pF
C _{io}	A or B port	$V_O = V_{CCA/B}$ or GNE)	3.3 V	3.3 V		6				pF

 $[\]begin{array}{ll} \hbox{(1)} & V_{CCO} \mbox{ is the } V_{CC} \mbox{ associated with the output port.} \\ \hbox{(2)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \\ \end{array}$



****室街®N74LVC1T45 Q1"供应商**

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (see Figure 1)

PARAMETER	FROM	TO (OUTDUT)	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	A	В	3	20.7	2.2	13.3	1.7	11.3	1.4	10.2	ns
t _{PHL}		ь	2.8	17.3	2.2	11.5	1.8	10.1	1.7	10	115
t _{PLH}	В	^	3	20.7	2.3	19	2.1	18.5	1.9	18.1	20
t _{PHL}	В	Α	2.8	17.3	2.1	15.9	2	15.6	1.8	15.2	ns
t _{PHZ}	DIR	۸	5.2	22.7	4.8	21.5	4.7	21.4	5.1	20.1	ns
t_{PLZ}	DIK	A	2.3	13.5	2.1	13.5	2.4	13.7	3.1	13.9	113
t _{PHZ}	DIR	В	7.4	27.9	4.9	14.5	3.6	13.3	2.3	11.2	20
t_{PLZ}	DIK	ь	4.2	19	2.2	12.2	2.3	11.4	2.0	9.4	ns
t _{PZH} (1)	DIR	Δ.		39.7		31.2		29.9		27.5	20
t _{PZL} ⁽¹⁾	DIK	Α		45.2		30.4		28.9		26.4	ns
t _{PZH} ⁽¹⁾	DIR	В		34.2		26.8		25		24.1	20
t _{PZL} ⁽¹⁾	ЫK	В		40.7		33		31.5		30.1	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 2.5 \text{ V} \pm 0.2 \text{ V}$ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	2.3	19	1.5	11.5	1.3	9.4	1.1	8.1	ns
t _{PHL}		Ь	2.1	15.9	1.4	10.5	1.3	8.4	0.9	7.6	115
t _{PLH}	В	^	2.2	13.3	1.5	11.5	1.4	11	1	10.5	20
t _{PHL}	Ь	A	2.2	11.5	1.4	10.7	1.3	10	0.9	9.2	ns
t _{PHZ}	DIR	۸	3	11.1	2.1	11.1	2.3	11.1	3.2	11.1	ns
t _{PLZ}	DIK	A	1.3	8.9	1.3	8.9	1.3	8.9	1	8.8	113
t _{PHZ}	DIR	В	6.5	26.7	4.1	14.4	3.0	13.2	1.9	10.1	20
t _{PLZ}	DIK	ь	3.5	21.9	2.2	12.6	2.5	11.4	1.6	8.3	ns
t _{PZH} (1)	DID	^		35.2		24.1		22.4		18.8	
t _{PZL} ⁽¹⁾	DIR	А		38.2		24.9		23.2		19.3	ns
t _{PZH} (1)	DIB	В		27.9		20.4		18.3		16.9	20
t _{PZL} ⁽¹⁾	DIR	Б		27		21.6		19.5		18.7	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

Copyright © 2006–2009, Texas Instruments Incorporated

Submit Documentation Feedback



Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = ±0.15	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		3.3 V V	V _{CCB} = ±0.5		UNIT
	(INPUT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	2.1	18.5	1.4	11	0.7	8.8	0.7	7.4	ns
t _{PHL}	А	Б	2	15.6	1.3	10	0.8	8	0.7	7	115
t _{PLH}	В	A	1.7	11.3	1.3	9.4	0.7	8.8	0.6	8.4	no
t _{PHL}	ь	A	1.8	10.1	1.3	8.4	0.8	8	0.7	7.5	ns
t _{PHZ}	DIR	А	2.3	10.3	2.4	10.3	1.5	10.3	2.4	10.3	ns
t _{PLZ}	DIK	A	1.8	8.6	1.6	8.6	1.9	8.7	2.0	8.7	113
t _{PHZ}	DIR	В	5.4	27.5	3.9	13.1	2.9	11.8	1.7	9.8	nc
t _{PLZ}	DIK	Б	2.3	17.5	2.1	10.8	2.4	10.1	1.5	7.9	ns
t _{PZH} ⁽¹⁾	DIR	А		28.8		20.2		18.9		16.3	no
t _{PZL} ⁽¹⁾	DIK	A		37.6		21.5		19.8		17.3	ns
t _{PZH} (1)	DIB	В		27.1		19.6		17.5		16.1	no
t _{PZL} ⁽¹⁾	DIR	Б		25.9		20.3		18.3		17.3	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 5 \text{ V} \pm 0.5 \text{ V}$ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.8 V ±0.15 V		V _{CCB} = 2.5 V ±0.2 V		V _{CCB} = 3.3 V ±0.3 V		V _{CCB} = 5 V ±0.5 V		UNIT
	(INPOT)		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t _{PLH}	Α	В	1.9	18.1	1	10.5	0.6	8.4	0.5	6.9	no
t _{PHL}		Б	1.8	15.2	0.9	9.2	0.7	7.5	0.5	6.5	ns
t _{PLH}	В	А	1.4	10.2	1	8.1	0.7	7.4	0.5	6.9	
t _{PHL}	В	A	1.7	10	0.9	7.6	0.7	7	0.5	6.5	ns
t _{PHZ}	DIR	۸	2.1	8.4	2.0	8.4	2.2	8.5	2.0	8.4	ns
t _{PLZ}	DIK	Α	0.9	6.8	1	6.8	1	6.7	0.9	6.7	113
t _{PHZ}	DIR	В	4.8	26.2	2.5	14.8	1	11.5	1.7	9.5	no
t_{PLZ}	DIK	Б	2.6	17.8	2.0	10.4	2.5	10	1.6	7.5	ns
t _{PZH} ⁽¹⁾	DIB	۸		28		18.5		17.4		14.4	
t _{PZL} (1)	DIR	Α		36.2		22.4		18.5		16	ns
t _{PZH} (1)	DIR	В		24.9		17.3		15.1		13.6	
t _{PZL} ⁽¹⁾	ЫK	В		23.6		17.6		16		14.9	ns

⁽¹⁾ The enable time is a calculated value, derived using the formula shown in the enable times section.

SCES677A - SEPTEMBER 2006-REVISED AUGUST 2009



****室街®N74LVC1T45 Q1"供应商**

Operating Characteristics

 $T_{\Delta} = 25^{\circ}C$

$I_A = 25^{\circ}$.						
P	ARAMETER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	$V_{CCA} = V_{CCB} = 3.3 V$	V _{CCA} = V _{CCB} = 5 V	UNIT
C (1)	A-port input, B-port output	C _L = 0 pF, f = 10 MHz,	3	4	4	4	, r.C
C _{pdA} (1)	B-port input, A-port output	$t_r = t_f = 1 \text{ ns}$	18	19	20	21	- pF
C (1)	A-port input, B-port output	$C_L = 0 \text{ pF},$	18	19	20	21	, r.C
C _{pdB} ⁽¹⁾	B-port input, A-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	3	4	4	4	- pF

⁽¹⁾ Power dissipation capacitance per transceiver

Power-Up Considerations

A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. To guard against such power-up problems, take the following precautions:

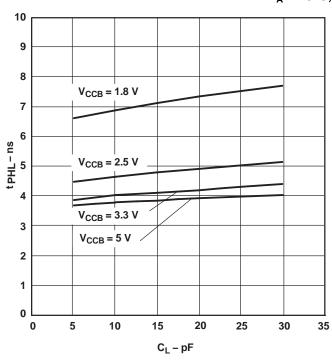
- 1. Connect ground before any supply voltage is applied.
- 2. Power up V_{CCA}.
- 3. V_{CCB} can be ramped up along with or after V_{CCA} .

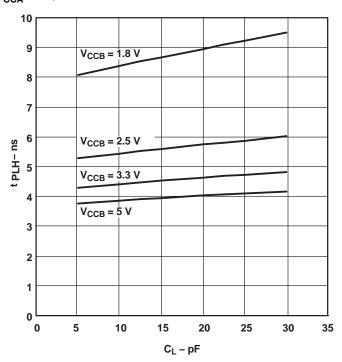
Submit Documentation Feedback



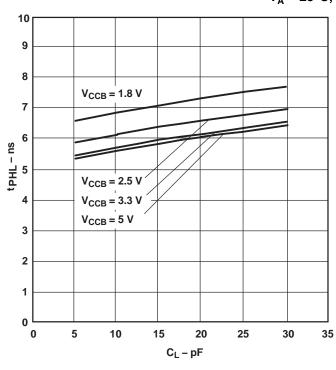
TYPICAL CHARACTERISTICS

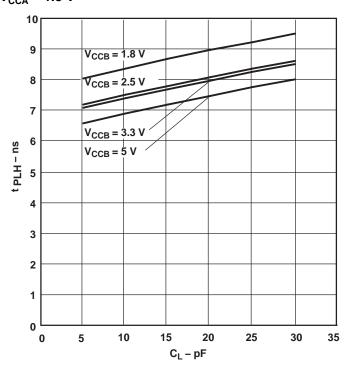
TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE $T_{A}=25^{\circ}\text{C},\,V_{\text{CCA}}=1.8\;\text{V}$





TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE $\rm T_A = 25^{\circ}C, \, V_{CCA} = 1.8 \; V$

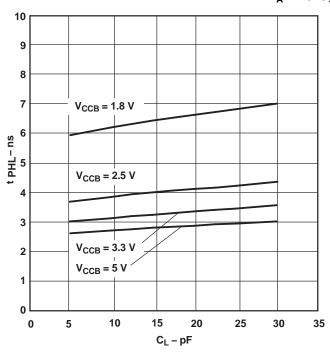


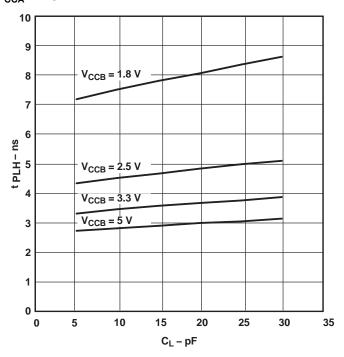


www.#sogN741 VC1T45 Q1"供应商

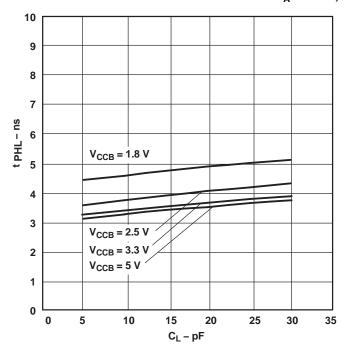
TYPICAL CHARACTERISTICS (continued)

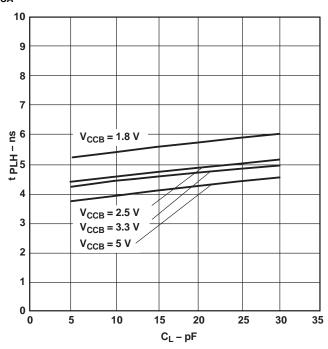
TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE $\rm T_A=25^{\circ}C,\,V_{CCA}=2.5\;V$





TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE $T_{\text{A}} = 25^{\circ}\text{C}, \, V_{\text{CCA}} = 2.5 \, \text{V}$

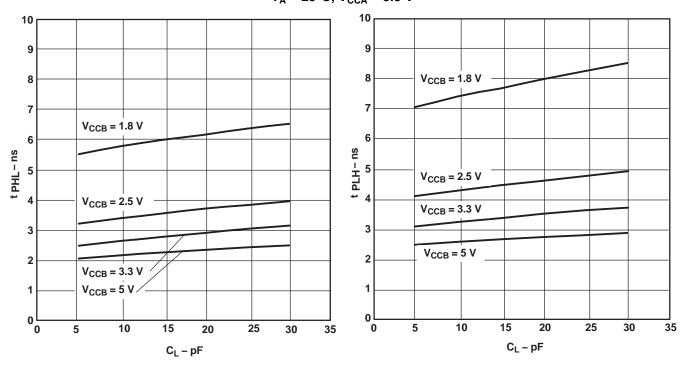




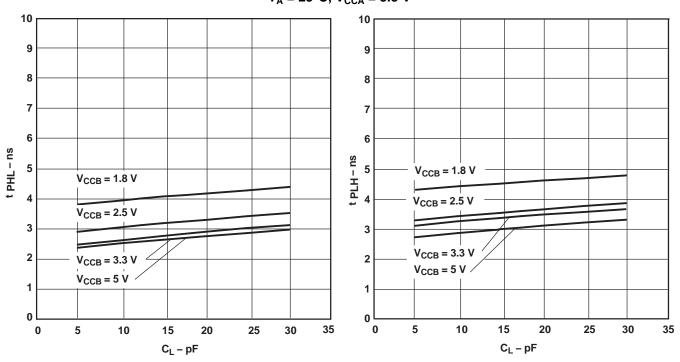


TYPICAL CHARACTERISTICS (continued)

TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE $\rm T_A = 25^{\circ}C, \, V_{CCA} = 3.3 \; V$



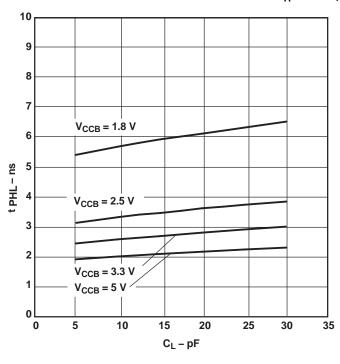
TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE T_{A} = 25°C, V_{CCA} = 3.3 V

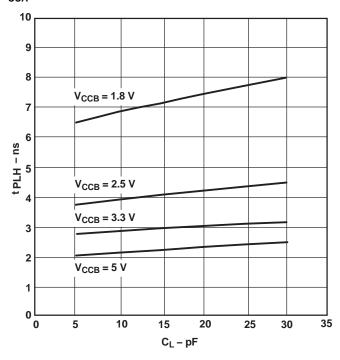


<u>₩豐梅♥N74LVC1T45 Q1"供应商</u>

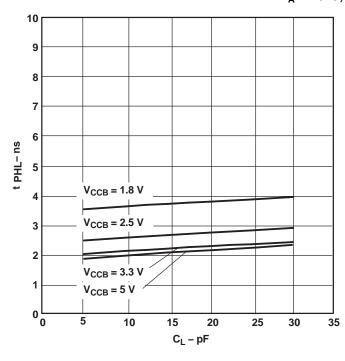
TYPICAL CHARACTERISTICS (continued)

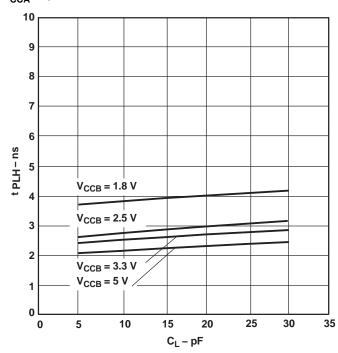
TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE T_{A} = 25°C, V_{CCA} = 5 V





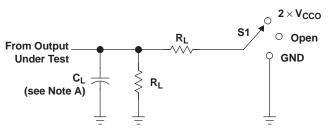
TYPICAL PROPAGATION DELAY (B to A) vs LOAD CAPACITANCE T_{A} = 25°C, V_{CCA} = 5 V







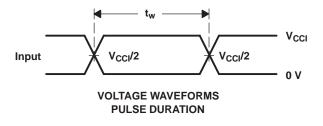
PARAMETER MEASUREMENT INFORMATION

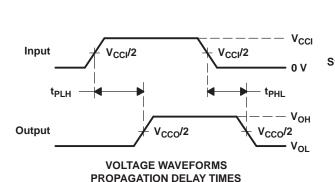


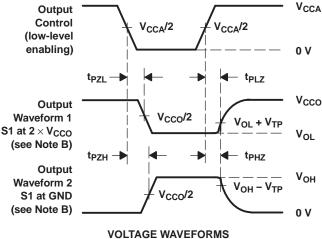
TEST	S1
t _{pd}	Open
t _{PLZ} /t _{PZL}	$2 \times V_{CCO}$
t _{PHZ} /t _{PZH}	GND

LOAD CIRCUIT

V _{CCO}	CL	RL	V _{TP}
1.8 V ± 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
3.3 V \pm 0.3 V	15 pF	2 k Ω	0.3 V
5 V ± 0.5 V	15 pF	2 k Ω	0.3 V







ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.

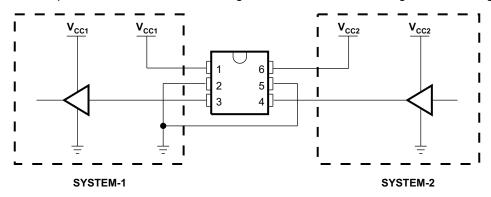
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $dv/dt \geq$ 1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd} .
- H. V_{CCI} is the V_{CC} associated with the input port.
- I. V_{CCO} is the V_{CC} associated with the output port.
- J. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms

₩₩##®™741 VC1T45 Q1"供应商

APPLICATION INFORMATION

Figure 2 shows an example of the SN74LVC1T45 being used in a unidirectional logic level-shifting application.

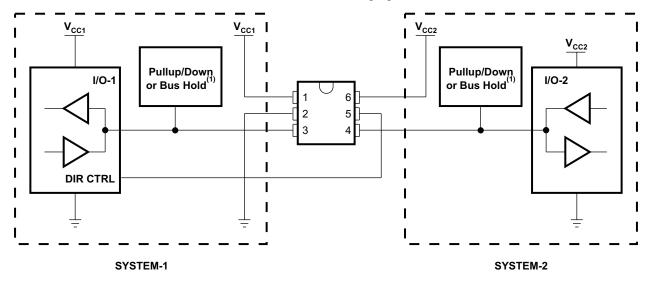


PIN	NAME	FUNCTION	DESCRIPTION
1	V _{CCA}	V _{CC1}	SYSTEM-1 supply voltage (1.65 V to 5.5 V)
2	GND	GND	Device GND
3	Α	OUT	Output level depends on V _{CC1} voltage.
4	В	IN	Input threshold value depends on V _{CC2} voltage.
5	DIR	DIR	GND (low level) determines B-port to A-port direction.
6	V _{CCB}	V _{CC2}	SYSTEM-2 supply voltage (1.65 V to 5.5 V)

Figure 2. Unidirectional Logic Level-Shifting Application



Figure 3 shows the SN74LVC1T45 being used in a bidirectional logic level-shifting application. Since the SN74LVC1T45 does not have an output-enable (OE) pin, the system designer should take precautions to avoid bus contention between SYSTEM-1 and SYSTEM-2 when changing directions.



The following table shows data transmission from SYSTEM-1 to SYSTEM-2 and then from SYSTEM-2 to SYSTEM-1.

STATE	DIR CTRL	I/O-1	I/O-2	DESCRIPTION
1	Н	Out	In	SYSTEM-1 data to SYSTEM-2
2	Н	Hi-Z	Hi-Z	SYSTEM-2 is getting ready to send data to SYSTEM-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on pullup or pulldown. (1)
3	L	Hi-Z	Hi-Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on pullup or pulldown. (1)
4	L	Out	In	SYSTEM-2 data to SYSTEM-1

(1) SYSTEM-1 and SYSTEM-2 must use the same conditions, i.e., both pullup or both pulldown.

Figure 3. Bidirectional Logic Level-Shifting Application

Enable Times

Calculate the enable times for the SN74LVC1T45 using the following formulas:

- t_{PZH} (DIR to A) = t_{PLZ} (DIR to B) + t_{PLH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the SN74LVC1T45 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.



PACKAGE OPTION ADDENDUM

查询"SN74LVC1T45-Q1"供应商

11-Sep-2009

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Pa	ackage Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
SN74LVC1T45TDCKRQ1	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN74LVC1T45-Q1:

- Catalog: SN74LVC1T45
- Enhanced Product: SN74LVC1T45-EP

NOTE: Qualified Version Definitions:

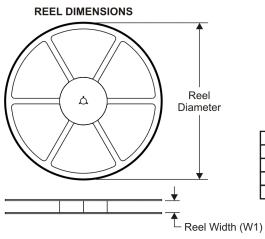
- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications



查询"\$N74LVC1T45-Q1"供应商

20-Jul-2010

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

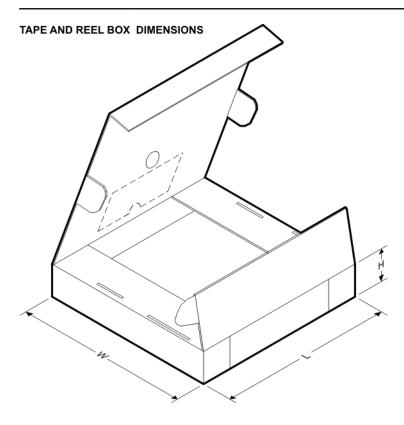
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1T45TDCKRQ1	SC70	DCK	6	3000	180.0	8.4	2.25	2.4	1.22	4.0	8.0	Q3





查询"\$N74LVC1T45-Q1"供应商

20-Jul-2010

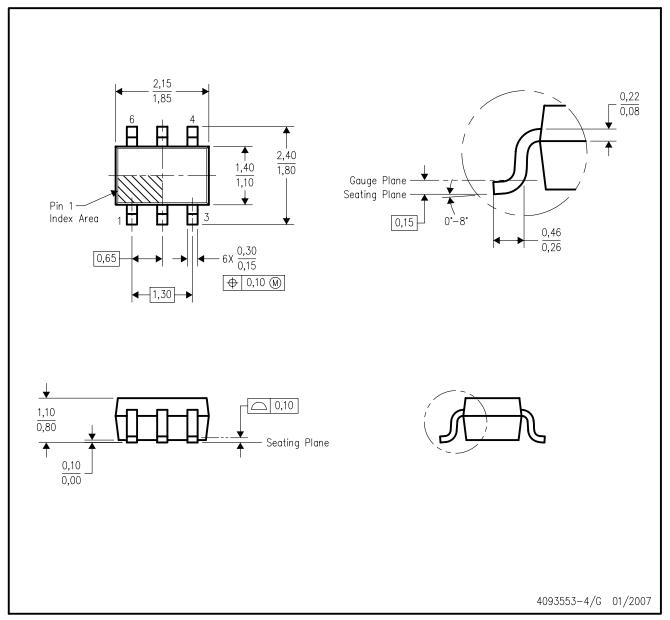


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1T45TDCKRQ1	SC70	DCK	6	3000	202.0	201.0	28.0

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE

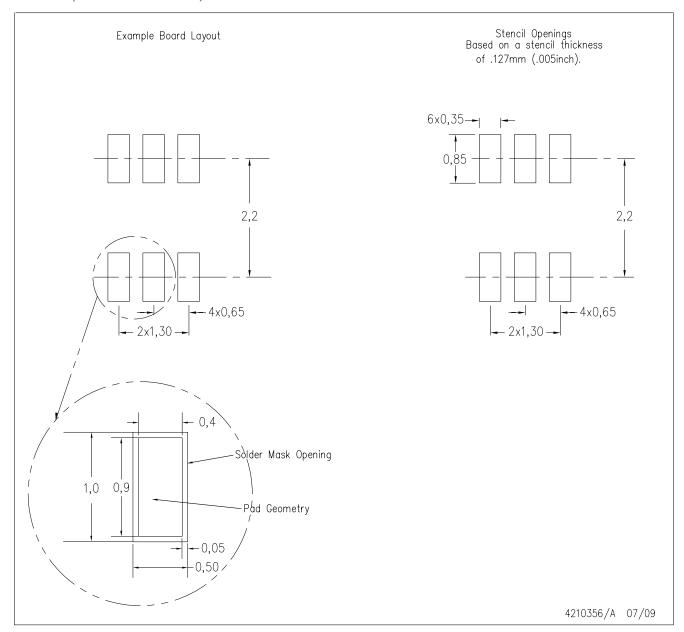


NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AB.



DCK (R-PDSO-G6)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



查询"SN74LVC1T45-Q1"供应商

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Amplifiers	amplifier.ti.com	Audio	www.ti.com/audio
Data Converters	dataconverter.ti.com	Automotive	www.ti.com/automotive
DLP® Products	www.dlp.com	Communications and Telecom	www.ti.com/communications
DSP	<u>dsp.ti.com</u>	Computers and Peripherals	www.ti.com/computers
Clocks and Timers	www.ti.com/clocks	Consumer Electronics	www.ti.com/consumer-apps
Interface	interface.ti.com	Energy	www.ti.com/energy
Logic	logic.ti.com	Industrial	www.ti.com/industrial
Power Mgmt	power.ti.com	Medical	www.ti.com/medical
Microcontrollers	microcontroller.ti.com	Security	www.ti.com/security
RFID	www.ti-rfid.com	Space, Avionics & Defense	www.ti.com/space-avionics-defense
RF/IF and ZigBee® Solutions	www.ti.com/lprf	Video and Imaging	www.ti.com/video
		Wireless	www.ti.com/wireless-apps